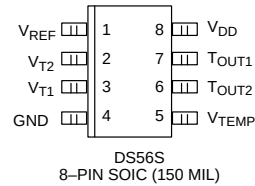


FEATURES

- Factory calibrated for sensitivity of $+6.20 \text{ mV}/^{\circ}\text{C}$ and thermometer accuracy of $\pm 2.0^{\circ}\text{C}$ over the 0°C to 85°C range and $\pm 3^{\circ}\text{C}$ over the 40°C to 0°C and $+85^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ range.
- Measurement range of -40°C to $+125^{\circ}\text{C}$
- Integrated temperature sensor and voltage reference
- Two independent temperature setpoints with respective logic outputs with set hysteresis
- Narrow-body SO8 (150mil) package
- Wide power supply range ($2.7\text{V} \leq V_{\text{DD}} \leq 5.5\text{V}$)
- Functionally-compatible with LM56xIM
- Applications include monitoring disk drives, printers, office equipment, HVAC, appliances, or any power/cost/temperature-sensitive environments.

PIN ASSIGNMENT



PIN DESCRIPTION

V_{REF}	– Bandgap Voltage Reference Output
V_{T2}	– Temperature Trip Point 2
V_{T1}	– Temperature Trip Point 1
GND	– Ground
V_{TEMP}	– Temp Sensor Output Voltage
T_{OUT2}	– Thermostat Output for Trip Point 2
T_{OUT1}	– Thermostat Output for Trip Point 1
V_{DD}	– Power Supply Voltage (2.7V to 5.5V)

DESCRIPTION

The DS56 has two independent open-drain thermostat outputs and respective trip point inputs. The trippoints are set with external resistors that divide down the 1.25V internal bandgap voltage reference. The voltage resulting from this resistive division is compared with the voltage corresponding to the device's junction temperature to define the thermostat output logic state. The internal temperature sensor has a typical sensitivity of $+6.2\text{mV}/^{\circ}\text{C}$ and DC offset of $+395 \text{ mV}$ at 0°C . Both thermostat outputs have 5°C of hysteresis.

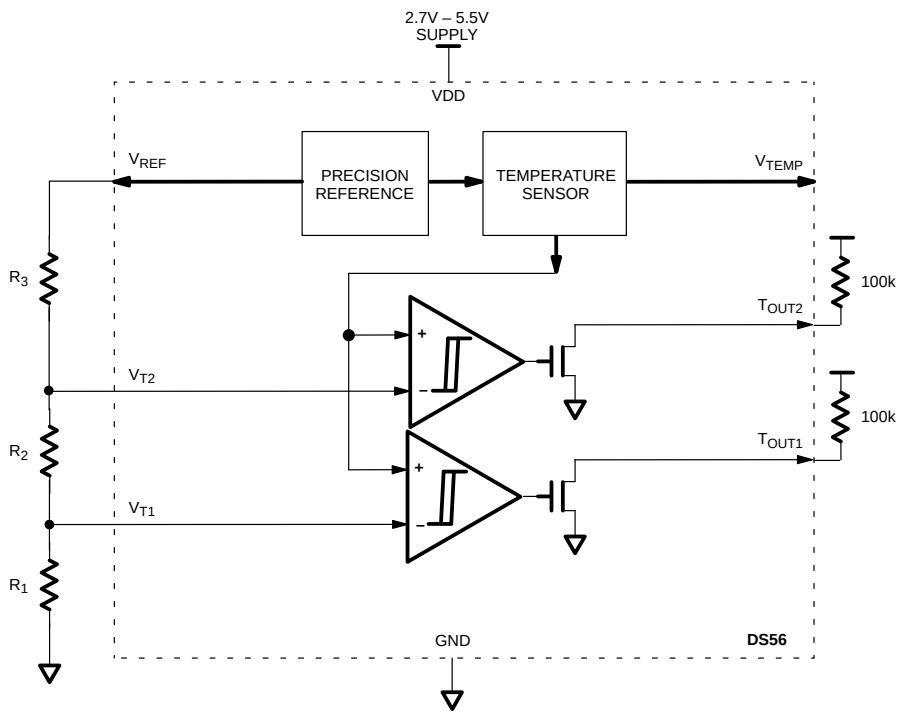
For applications that require temperature measurement as well as control, the temperature sensor voltage is brought out to a pin.

The DS56 is packaged in a compact 150 mil 8-pin SOIC. Applications include disk drives, printers, office equipment, HVAC, appliances, or any power/cost/temperature-sensitive environments.

DETAILED PIN DESCRIPTION Table 1

PIN	SYMBOL	TYPE	DESCRIPTION
1	V _{REF}	Analog output	Bandgap output 1.25V (nom) voltage reference output
2	V _{T2}	Analog input	Trip point 2 input associated with thermostat output 2.
3	V _{T1}	Analog input	Trip point 1 input associated with thermostat output 1.
4	GND	GND	Ground pin.
5	V _{TEMP}	Analog output	Temperature sensor output. (+6.2 T _{DegC} + 395) mV.
6	T _{OUT2}	Digital output (open-drain)	Thermostat output 2. Active low output corresponding to trip point 2. Typical hysteresis is 5.0°C.
7	T _{OUT1}	Digital output (open-drain)	Thermostat output 1. Active low output corresponding to trip point 1. Typical hysteresis is 5.0°C.
8	V _{DD}	V _{DD}	Supply Voltage 2.7V – 5.5V input power pin.

DS56 FUNCTIONAL BLOCK DIAGRAM Figure 1



OVERVIEW

A block diagram of the DS56 is shown in Figure 1. The DS56 consists of three major components:

1. Precision bandgap voltage reference
2. Temperature sensor
3. Thermostat comparators

The DS56 incorporates an internal temperature sensor with a typical transfer function of (in mV with T expressed in °C):

$$V_{TEMP}(T) = 6.2T + 395$$

The voltage associated with this transfer function is output on the V_{TEMP} pin, which has a typical output impedance of 1.5k Ω .

The DS56 has two independent temperature comparators, each with its own input (or trip point) and output.

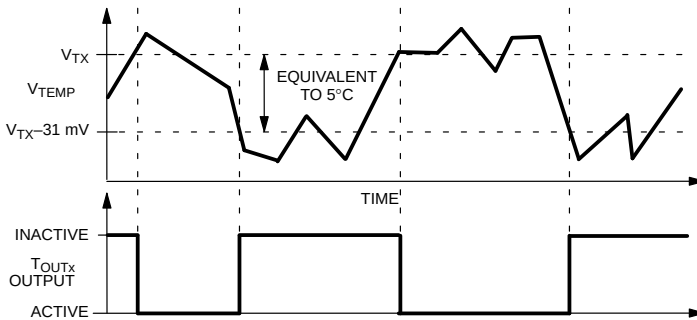
The comparison voltage (the V_{TEMP} transfer function) is the same for both comparators. Additionally, the hysteresis for both comparators is typically 5°C (31.0 mV).

The DS56 bandgap voltage reference is available on pin 1 to allow for a designer to set the trip point(s) by resistively dividing the reference voltage. One possible scenario is illustrated in Figure 1. For optimum performance, the V_{REF} pin should be connected to a 50 μ A load.

The comparator outputs are taken off-chip via open-drain FETs, thus requiring external pull-ups. The thermostat transfer function is illustrated in Figure 2.

The supply range of the DS56 is 2.7V to 5.5V, allowing for applications ranging from industrial control to battery-powered portable equipment.

THERMOSTAT OUTPUT TRANSFER FUNCTION Figure 2



ABSOLUTE MAXIMUM RATINGS*

Voltage on V_{DD}	(GND–0.3V) to +7.0V
Input Current at any pin	5.0 mA
Package Input Current	20 mA
Operating Temperature	–40°C to +125°C
Storage Temperature	–55°C to 150°C
ESD Susceptibility (Human Body Model)	1kV
Soldering Temperature (Note 2)	215°C for 60 seconds (Vapor Phase) 220°C for 15 seconds (IR)

* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

The Dallas Semiconductor DS56 is built to the highest quality standards and manufactured for long term reliability. All Dallas Semiconductor devices are made using the same quality materials and manufacturing methods. However, the DS56 is not exposed to environmental stresses, such as burn-in, that some industrial applications require. For specific reliability information on this product, please contact the factory in Dallas at (972) 371–4448.

RECOMMENDED DC OPERATING CONDITIONS: (–40°C to +125°C; $2.7V \leq V_{DD} \leq 5.5V$)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	V_{DD}		2.7		5.5	V	1

DC ELECTRICAL CHARACTERISTICS:

Power Supply (Note 3) (–40°C to +125°C; $2.7V \leq V_{DD} \leq 5.5V$)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
Supply Current	I_{DD}				225	μA	

DC ELECTRICAL CHARACTERISTICS:

Temperature Sensor (Note 3) (–40°C to +125°C; $2.7V \leq V_{DD} \leq 5.5V$)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
Trip Point Accuracy	TP_{ERR}	$-40^{\circ}C \leq T_A \leq 125^{\circ}C$			± 3	$^{\circ}C$	4
		$0^{\circ}C \leq T_A \leq 85^{\circ}C$			± 2		
V_{TEMP} Accuracy	T_{ERR}	$-40^{\circ}C \leq T_A \leq 125^{\circ}C$			± 3	$^{\circ}C$	5
		$0^{\circ}C \leq T_A \leq 85^{\circ}C$			± 2		
V_{TEMP} DC Offset		$T = 0^{\circ}C$		395		mV	
Sensor Gain	$\Delta V / \Delta T$			6.25		mV/ $^{\circ}C$	
Trip Point Hysteresis	TP_{HYST}		3.0	5.0	7.0	$^{\circ}C$	
Power Supply Regulation		$2.7V \leq V_{DD} \leq 3.3V$			± 2.3	mV	
		$3.0V \leq V_{DD} \leq 5.5V$			± 0.3	mV/V	
V_{TEMP} Output Impedance					1500	Ω	

DC ELECTRICAL CHARACTERISTICS:**Bandgap Voltage Reference V_{REF}** (-40°C to $+125^{\circ}\text{C}$; $2.7\text{V} \leq V_{DD} \leq 5.5\text{V}$)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
V_{REF} Output	V_{REF}		1.238	1.25	1.263	V	
Power Supply Regulation	$\Delta V_{REF}/\Delta V_{DD}$	$2.7\text{V} \leq V_{DD} \leq 3.3\text{V}$			± 1.45	mV	
		$30\text{V} \leq V_{DD} \leq 5.5\text{V}$			± 0.2	mV/V	
Load Regulation	$\Delta V_{REF}/\Delta I_L$	$+3.0\mu\text{A} \leq I_L \leq +50\mu\text{A}$			0.15	mV/ μA	

DC ELECTRICAL CHARACTERISTICS:**Trip Point Inputs V_{T1}/V_{T2}** (-40°C to $+125^{\circ}\text{C}$; $2.7\text{V} \leq V_{DD} \leq 5.5\text{V}$)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
Input Bias Current	I_{BIAS}				300	nA	
Input Range	V_{TIN}		0		($V_{DD} - 1.0$)	V	

DC ELECTRICAL CHARACTERISTICS:**Thermostat Outputs T_{OUT1}/T_{OUT2}** (-40°C to $+125^{\circ}\text{C}$; $2.7\text{V} \leq V_{DD} \leq 5.5\text{V}$)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNITS	NOTES
Logical "1" Output Leakage Current	I_{OUT1}	$V_{DD} = 5.0\text{V}$			1.0	μA	
LOGICAL "0" Output Voltage	V_{OUT0}	$I_{OUT} = +50\mu\text{A}$			0.4	V	

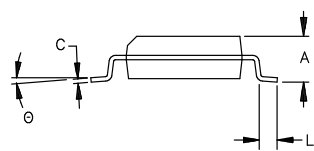
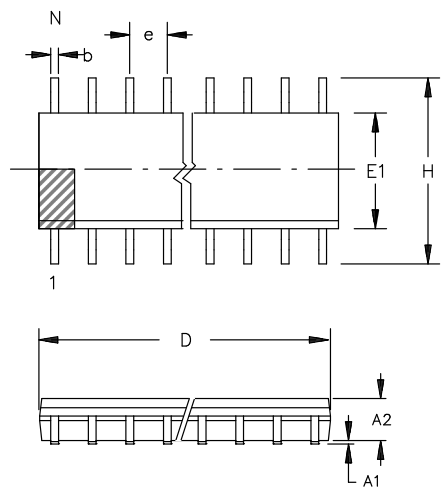
NOTES:

1. All voltages are referenced to ground, unless otherwise specified.
2. Solder according to IPC standards.
3. Specified for V_{TEMP} sourcing $1.0\mu\text{A}$ (max) and V_{REF} load current = $50\mu\text{A}$.
4. Includes error associated with internal temperature sensor, bandgap voltage V_{REF} , and comparator offset. External resistance tolerance and temperature coefficient not included in this spec.
5. Thermometer error (expressed in $^{\circ}\text{C}$) is the difference between $[V_O(T) - 395]/6.20$ and the DS56 case temperature at $V_{DD} = 3.0\text{V}$, thus taking into account sensor error, DC offset error, sensor amplifier gain variations, and amplifier nonlinearity.

TYPICAL DS56 THERMOMETER ERROR Figure 3**TBD****TYPICAL DS56 V_{TEMP} TRANSFER FUNCTION Figure 4****TBD**

DS56 PHYSICAL DIMENSIONS

8-, 14-, AND 16-PIN SOIC (.150" BODY WIDTH)



PKG	8-PIN		14-PIN		16-PIN	
DIM	MIN	MAX	MIN	MAX	MIN	MAX
A IN. MM	0.053 1.35	0.069 1.75	0.053 1.35	0.069 1.75	0.053 1.35	0.069 1.75
A1 IN. MM	0.004 0.10	0.010 0.25	0.004 0.10	0.010 0.25	0.004 0.10	0.010 0.25
A2 IN. MM	0.048 1.24	0.062 1.57	0.048 1.24	0.062 1.57	0.048 1.24	0.062 1.57
b IN. MM	0.012 0.30	0.020 0.50	0.012 0.30	0.020 0.50	0.012 0.30	0.020 0.50
C IN MM	0.007 0.17	0.011 0.28	0.007 0.17	0.011 0.28	0.007 0.17	0.011 0.28
D IN. MM	0.188 4.78	0.196 4.98	0.337 8.55	0.344 8.74	0.386 9.80	0.393 9.98
e IN. MM	0.050 BSC 1.27 BSC		0.050 BSC 1.27 BSC		0.050 BSC 1.27 BSC	
E1 IN. MM	0.150 3.81	0.158 4.01	0.150 3.81	0.158 4.01	0.150 3.81	0.158 4.01
H IN. MM	0.230 5.84	0.244 6.20	0.230 5.84	0.244 6.20	0.230 5.84	0.244 6.20
L IN. MM	0.016 0.40	0.050 0.89	0.016 0.40	0.050 0.89	0.016 0.40	0.050 0.89
Θ	0°	8°	0°	8°	0°	8°